TOSHIBA Bipolar Linear Integrated Circuit   Silicon Monolithic

TA78L05PF, TA78L06PF, TA78L07PF, TA78L08PF, TA78L09PF, TA78L10PF, TA78L12PF, TA78L15PF

5 V, 6 V, 7V, 8 V, 9 V, 10 V, 12 V, 15V
3-Terminal Positive Voltage Regulators

Housed in a very small and thin PS-8 package, the TA78L**PF series of fixed-voltage monolithic integrated circuit voltage regulators is designed for a wide range of applications. One of these regulators can drive up to 0.15 A of output current.
The series offers devices with low-output voltages: 5 V, 6 V, 7 V, 8 V, 9 V, 10 V, 12 V, and 15 V.

Features

- Maximum output current: 0.15 A
- Output voltage accuracy: $V_{OUT} \pm 4\%$ (@T_j = 25°C)
- Protection function: overheating/overcurrent
- Package type: PS-8 is a flat lead, 8-pin package.
  This is smaller and thinner than the previous PW-Mini, with a 47% decrease in height and a 54% decrease in mounting area.
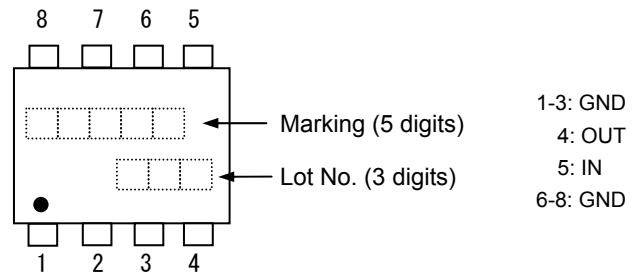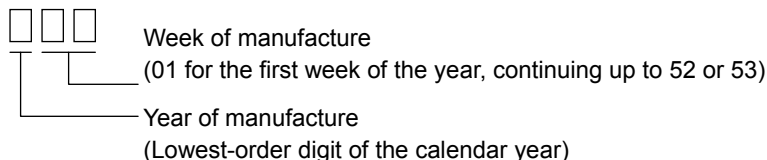- Lead-free products
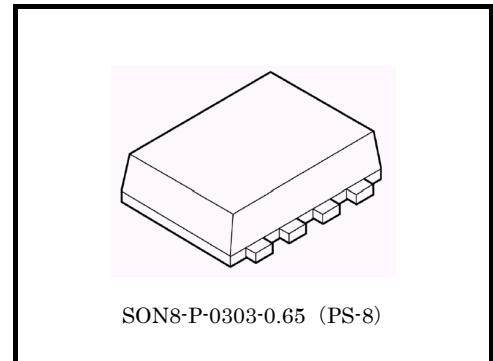
SON8-P-0303-0.65（PS-8）

Weight: 0.08 g (typ.)

Pin Assignment/Marking

Product No.	Marking (5 digits)
TA78L05PF	78L05
TA78L06PF	78L06
TA78L07PF	78L07
TA78L08PF	78L08
TA78L09PF	78L09
TA78L10PF	78L10
TA78L12PF	78L12
TA78L15PF	78L15

1-3: GND
4: OUT
5: IN
6-8: GND

*(∉) on the lower left of the marking indicates Pin 1.

* Weekly code: (Three digits)

Week of manufacture
(01 for the first week of the year, continuing up to 52 or 53)

Year of manufacture
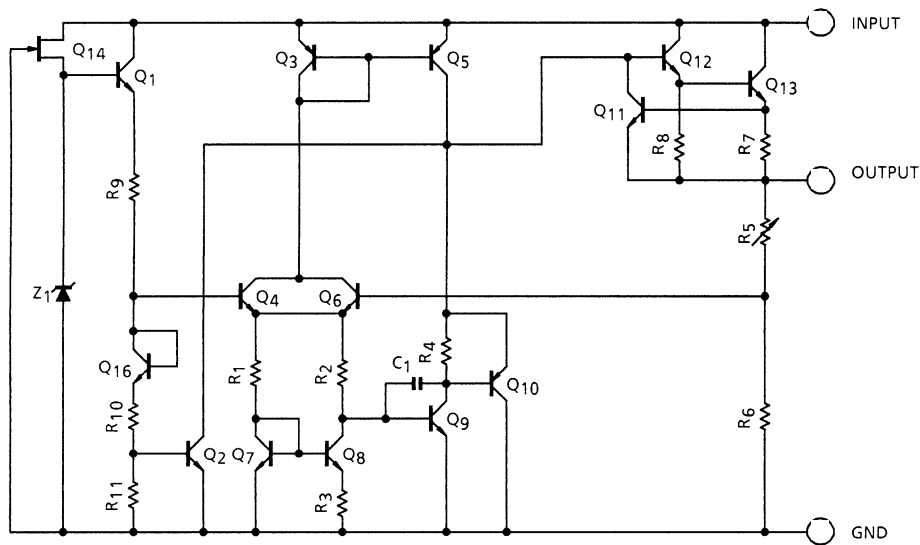(Lowest-order digit of the calendar year)

How to Order

Product No.	Packing Type and Unit for Orders
TA78L**PF (TE85L,F)	Embossed-tape packing: 2000 (1 tape)

Note 1: In the actual product number, "**" is replaced by the output voltage of the product.

Block Diagram

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Input voltage		V_{IN}	35	V
Output current		I_{OUT}	0.15	A
Operating temperature		T_{opr}	−30~85	°C
Junction temperature		T_j	150	°C
Storage temperature		T_{stg}	−55~150	°C
Power dissipation	(Note 4a)	P_D	1.3	W
Power dissipation	(Note 4b)	P_D	0.62	W

Note 2: Do not apply external current and voltage (including negative voltage) to pins other than those specified.

Note 3: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal resistance

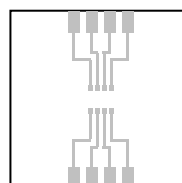| Characteristics	Symbol	Rating	Unit
Thermal resistance (junction to ambient) (Note 4a)	$R_{th(j-a)}$	97	°C/W
Thermal resistance (junction to ambient) (Note 4b)	$R_{th(j-a)}$	202	°C/W

Note 4:

(a) Device mounted on a glass-epoxy board
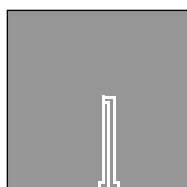
FR-4
25.4 × 25.4 × 1.6
Unit: (mm)
Cu base thickness
35 μm

(b) Device mounted on a glass-epoxy board

FR-4
25.4 × 25.4 × 1.6
Unit: (mm)
Cu base thickness
35 μm

TA78L05PF
Electrical Characteristics
(V_{IN} = 10 V, I_{OUT} = 40 mA, C_{IN} = 0.33 µF, C_{OUT} = 0.1 µF, 0°C ≤ T_j ≤ 125°C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Output voltage	V_{OUT}	1	T_j = 25°C		4.8	5.0	5.2	V
Line regulation	Reg·line	1	T_j = 25°C	7.0 V ≤ V_{IN} ≤ 20 V	—	55	150	mV
				8.0 V ≤ V_{IN} ≤ 20 V	—	45	100	
Load regulation	Reg·load	1	T_j = 25°C	1.0 mA ≤ I_{OUT} ≤ 100 mA	—	11	60	mV
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	5.0	30	
Output voltage	V_{OUT}	1	T_j = 25°C	7.0 V ≤ V_{IN} ≤ 20 V, 1.0 mA ≤ I_{OUT} ≤ 40 mA	4.75	—	5.25	V
				1.0 mA ≤ I_{OUT} ≤ 70 mA	4.75	—	5.25	
Quiescent current	I_B	1	T_j = 25°C		—	3.1	6.0	mA
			T_j = 125°C		—	—	5.5	
Quiescent current change	ΔI_B	1	T_j = 25°C	8.0 V ≤ V_{IN} ≤ 20 V	—	—	1.5	mA
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	—	0.1	
Output noise voltage	V_{NO}	2	Ta = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	40	—	µV$_{rms}$
Ripple rejection ratio	R.R.	3	f = 120 Hz, 8.0 V ≤ V_{IN} ≤ 18 V, T_j = 25°C		41	49	—	dB
Dropout voltage	V_D	1	T_j = 25°C, I_{OUT} = 150 mA		—	2.0	—	V
Average temperature coefficient of output voltage	T_{CVO}	1	I_{OUT} = 5 mA		—	−0.6	—	mV/°C

TA78L06PF
Electrical Characteristics
(V_{IN} = 11 V, I_{OUT} = 40 mA, C_{IN} = 0.33 µF, C_{OUT} = 0.1 µF, 0°C ≤ T_j ≤ 125°C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Output voltage	V_{OUT}	1	T_j = 25°C		5.76	6.0	6.24	V
Line regulation	Reg·line	1	T_j = 25°C	8.1 V ≤ V_{IN} ≤ 21 V	—	50	150	mV
				9.0 V ≤ V_{IN} ≤ 21 V	—	45	110	
Load regulation	Reg·load	1	T_j = 25°C	1.0 mA ≤ I_{OUT} ≤ 100 mA	—	12	70	mV
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	5.5	35	
Output voltage	V_{OUT}	1	T_j = 25°C	8.1 V ≤ V_{IN} ≤ 21 V, 1.0 mA ≤ I_{OUT} ≤ 40 mA	5.7	—	6.3	V
				1.0 mA ≤ I_{OUT} ≤ 70 mA	5.7	—	6.3	
Quiescent current	I_B	1	T_j = 25°C		—	3.1	6.0	mA
			T_j = 125°C		—	—	5.5	
Quiescent current change	ΔI_B	1	T_j = 25°C	9.0 V ≤ V_{IN} ≤ 20 V	—	—	1.5	mA
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	—	0.1	
Output noise voltage	V_{NO}	2	Ta = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	40	—	µV$_{rms}$
Ripple rejection ratio	R.R.	3	f = 120 Hz, 9.0 V ≤ V_{IN} ≤ 19 V, T_j = 25°C		39	47	—	dB
Dropout voltage	V_D	1	T_j = 25°C, I_{OUT} = 150 mA		—	2.0	—	V
Average temperature coefficient of output voltage	T_{CVO}	1	I_{OUT} = 5 mA		—	−0.7	—	mV/°C

TA78L07PF
Electrical Characteristics
(V_{IN} = 12 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μF, C_{OUT} = 0.1 μF, 0°C ≤ T_j ≤ 125°C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Output voltage	V_{OUT}	1	T_j = 25°C		6.72	7.0	7.28	V
Line regulation	Reg·line	1	T_j = 25°C	9.2 V ≤ V_{IN} ≤ 22 V	—	50	160	mV
				10 V ≤ V_{IN} ≤ 22 V	—	45	115	
Load regulation	Reg·load	1	T_j = 25°C	1.0 mA ≤ I_{OUT} ≤ 100 mA	—	13	75	mV
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	6.0	40	
Output voltage	V_{OUT}	1	T_j = 25°C	9.2 V ≤ V_{IN} ≤ 22 V, 1.0 mA ≤ I_{OUT} ≤ 40 mA	6.65	—	7.35	V
				1.0 mA ≤ I_{OUT} ≤ 70 mA	6.65	—	7.35	
Quiescent current	I_B	1	T_j = 25°C		—	3.1	6.5	mA
			T_j = 125°C		—	—	6.0	
Quiescent current change	ΔI_B	1	T_j = 25°C	10 V ≤ V_{IN} ≤ 22 V	—	—	1.5	mA
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	—	0.1	
Output noise voltage	V_{NO}	2	Ta = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	50	—	μV$_{rms}$
Ripple rejection ratio	R.R.	3	f = 120 Hz, 10 V ≤ V_{IN} ≤ 20 V, T_j = 25°C		37	46	—	dB
Dropout voltage	V_D	1	T_j = 25°C, I_{OUT} = 150 mA		—	2.0	—	V
Average temperature coefficient of output voltage	T_{CVO}	1	I_{OUT} = 5 mA		—	−0.75	—	mV/°C

TA78L08PF
Electrical Characteristics
(V_{IN} = 14 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μF, C_{OUT} = 0.1 μF, 0°C ≤ T_j ≤ 125°C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Output voltage	V_{OUT}	1	T_j = 25°C		7.7	8.0	8.3	V
Line regulation	Reg·line	1	T_j = 25°C	10.5 V ≤ V_{IN} ≤ 23 V	—	20	175	mV
				11 V ≤ V_{IN} ≤ 23 V	—	12	125	
Load regulation	Reg·load	1	T_j = 25°C	1.0 mA ≤ I_{OUT} ≤ 100 mA	—	15	80	mV
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	7.0	40	
Output voltage	V_{OUT}	1	T_j = 25°C	10.5 V ≤ V_{IN} ≤ 23 V, 1.0 mA ≤ I_{OUT} ≤ 40 mA	7.6	—	8.4	V
				1.0 mA ≤ I_{OUT} ≤ 70 mA	7.6	—	8.4	
Quiescent current	I_B	1	T_j = 25°C		—	3.1	6.5	mA
			T_j = 125°C		—	—	6.0	
Quiescent current change	ΔI_B	1	T_j = 25°C	11 V ≤ V_{IN} ≤ 23 V	—	—	1.5	mA
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	—	0.1	
Output noise voltage	V_{NO}	2	Ta = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	60	—	μV$_{rms}$
Ripple rejection ratio	R.R.	3	f = 120 Hz, 12 V ≤ V_{IN} ≤ 23 V, T_j = 25°C		37	45	—	dB
Dropout voltage	V_D	1	T_j = 25°C, I_{OUT} = 150 mA		—	2.0	—	V
Average temperature coefficient of output voltage	T_{CVO}	1	I_{OUT} = 5 mA		—	−0.8	—	mV/°C

TA78L09PF
Electrical Characteristics

(V_{IN} = 15 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μF, C_{OUT} = 0.1 μF, 0°C ≤ T_j ≤ 125°C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Output voltage	V_{OUT}	1	T_j = 25°C		8.64	9.0	9.36	V
Line regulation	Reg·line	1	T_j = 25°C	11.4 V ≤ V_{IN} ≤ 24 V	—	80	200	mV
				12 V ≤ V_{IN} ≤ 24 V	—	20	160	
Load regulation	Reg·load	1	T_j = 25°C	1.0 mA ≤ I_{OUT} ≤ 100 mA	—	17	90	mV
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	8.0	45	
Output voltage	V_{OUT}	1	T_j = 25°C	11.4 V ≤ V_{IN} ≤ 24 V, 1.0 mA ≤ I_{OUT} ≤ 40 mA	8.55	—	9.45	V
				1.0 mA ≤ I_{OUT} ≤ 70 mA	8.55	—	9.45	
Quiescent current	I_B	1	T_j = 25°C		—	3.2	6.5	mA
			T_j = 125°C		—	—	6.0	
Quiescent current change	ΔI_B	1	T_j = 25°C	12 V ≤ V_{IN} ≤ 24 V	—	—	1.5	mA
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	—	0.1	
Output noise voltage	V_{NO}	2	Ta = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	65	—	μV$_{rms}$
Ripple rejection ratio	R.R.	3	f = 120 Hz, 12 V ≤ V_{IN} ≤ 24 V, T_j = 25°C		36	44	—	dB
Dropout voltage	V_D	1	T_j = 25°C, I_{OUT} = 150 mA		—	2.0	—	V
Average temperature coefficient of output voltage	T_{CVO}	1	I_{OUT} = 5 mA		—	−0.85	—	mV/°C

TA78L10PF
Electrical Characteristics

(V_{IN}=16 V, I_{OUT}=40 mA, C_{IN} = 0.33 μF, C_{OUT} = 0.1 μF, 0°C ≤ T_j ≤ 125°C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Output voltage	V_{OUT}	1	T_j = 25°C		9.6	10	10.4	V
Line regulation	Reg·line	1	T_j = 25°C	12.5 V ≤ V_{IN} ≤ 25 V	—	80	230	mV
				13 V ≤ V_{IN} ≤ 25 V	—	30	170	
Load regulation	Reg·load	1	T_j = 25°C	1.0 mA ≤ I_{OUT} ≤ 100 mA	—	18	90	mV
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	8.5	45	
Output voltage	V_{OUT}	1	T_j = 25°C	12.5 V ≤ V_{IN} ≤ 25 V, 1.0 mA ≤ I_{OUT} ≤ 40 mA	9.5	—	10.5	V
				1.0 mA ≤ I_{OUT} ≤ 70 mA	9.5	—	10.5	
Quiescent current	I_B	1	T_j = 25°C		—	3.2	6.5	mA
			T_j = 125°C		—	—	6.0	
Quiescent current change	ΔI_B	1	T_j = 25°C	13 V ≤ V_{IN} ≤ 25 V	—	—	1.5	mA
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	—	0.1	
Output noise voltage	V_{NO}	2	Ta = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	70	—	μV$_{rms}$
Ripple rejection ratio	R.R.	3	f = 120 Hz, 13 V ≤ V_{IN} ≤ 24 V, T_j = 25°C		36	43	—	dB
Dropout voltage	V_D	1	T_j = 25°C, I_{OUT} = 150 mA		—	2.0	—	V
Average temperature coefficient of output voltage	T_{CVO}	1	I_{OUT} = 5 mA		—	−0.9	—	mV/°C

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TA78L12PF
Electrical Characteristics
(V_{IN} = 19 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μF, C_{OUT} = 0.1 μF, 0°C ≤ T_j ≤ 125°C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Output voltage	V_{OUT}	1	T_j = 25°C		11.52	12	12.48	V
Line regulation	Reg·line	1	T_j = 25°C	14.5 V ≤ V_{IN} ≤ 27 V	—	120	250	mV
				16 V ≤ V_{IN} ≤ 27 V	—	100	200	
Load regulation	Reg·load	1	T_j = 25°C	1.0 mA ≤ I_{OUT} ≤ 100 mA	—	20	100	mV
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	10	50	
Output voltage	V_{OUT}	1	T_j = 25°C	14.5 V ≤ V_{IN} ≤ 27 V, 1.0 mA ≤ I_{OUT} ≤ 40 mA	11.4	—	12.6	V
				1.0 mA ≤ I_{OUT} ≤ 70 mA	11.4	—	12.6	
Quiescent current	I_B	1	T_j = 25°C		—	3.2	6.5	mA
			T_j = 125°C		—	—	6.0	
Quiescent current change	ΔI_B	1	T_j = 25°C	16 V ≤ V_{IN} ≤ 27 V	—	—	1.5	mA
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	—	0.1	
Output noise voltage	V_{NO}	2	Ta = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	80	—	μV$_{rms}$
Ripple rejection ratio	R.R.	3	f = 120 Hz, 15 V ≤ V_{IN} ≤ 25 V, T_j = 25°C		36	41	—	dB
Dropout voltage	V_D	1	T_j = 25°C, I_{OUT} = 150 mA		—	2.0	—	V
Average temperature coefficient of output voltage	T_{CVO}	1	I_{OUT} = 5 mA		—	−1.0	—	mV/°C

TA78L15PF
Electrical Characteristics
(V_{IN} = 23 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μF, C_{OUT} = 0.1 μF, 0°C ≤ T_j ≤ 125°C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Output voltage	V_{OUT}	1	T_j = 25°C		14.4	15	15.6	V
Line regulation	Reg·line	1	T_j = 25°C	17.5 V ≤ V_{IN} ≤ 30 V	—	130	300	mV
				20 V ≤ V_{IN} ≤ 30 V	—	110	250	
Load regulation	Reg·load	1	T_j = 25°C	1.0 mA ≤ I_{OUT} ≤ 100 mA	—	25	150	mV
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	12	75	
Output voltage	V_{OUT}	1	T_j = 25°C	17.5 V ≤ V_{IN} ≤ 30 V, 1.0 mA ≤ I_{OUT} ≤ 40 mA	14.25	—	15.75	V
				1.0 mA ≤ I_{OUT} ≤ 70 mA	14.25	—	15.75	
Quiescent current	I_B	1	T_j = 25°C		—	3.3	6.5	mA
			T_j = 125°C		—	—	6.0	
Quiescent current change	ΔI_B	1	T_j = 25°C	20 V ≤ V_{IN} ≤ 30 V	—	—	1.5	mA
				1.0 mA ≤ I_{OUT} ≤ 40 mA	—	—	0.1	
Output noise voltage	V_{NO}	2	Ta = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	90	—	μV$_{rms}$
Ripple rejection ratio	R.R.	3	f = 120 Hz, 18.5 V ≤ V_{IN} ≤ 28.5 V, T_j = 25°C		34	40	—	dB
Dropout voltage	V_D	1	T_j = 25°C, I_{OUT} = 150 mA		—	2.0	—	V
Average temperature coefficient of output voltage	T_{CVO}	1	I_{OUT} = 5 mA		—	−1.3	—	mV/°C

Electrical Characteristics for All Products
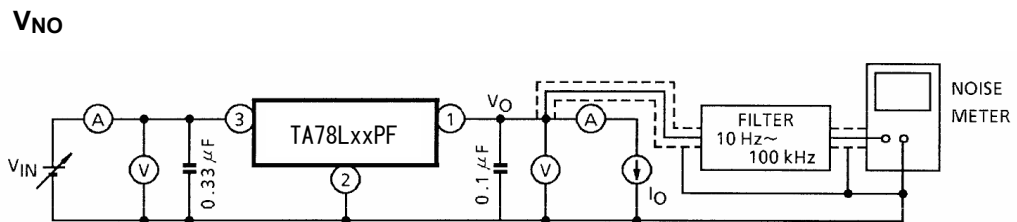
Generally, the characteristics of power supply ICs change according to temperature fluctuations.
The specification T_j = 25°C is based on a state where temperature increase has no effect (assuming no fluctuation in the characteristics) as ascertained by pulse tests.

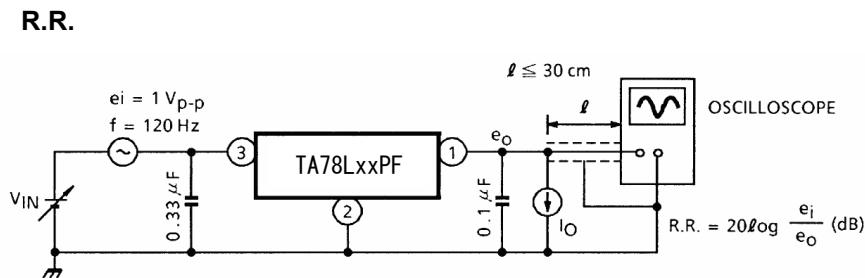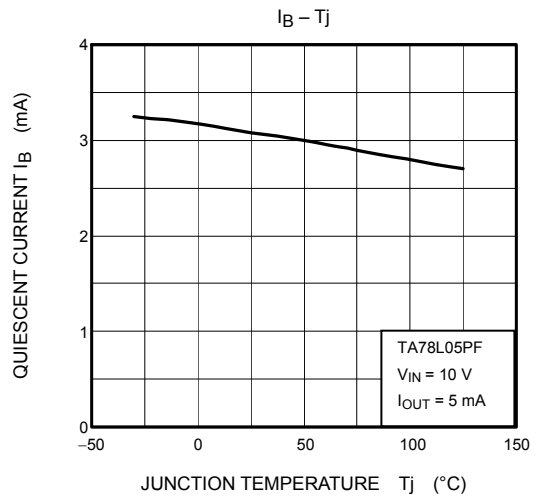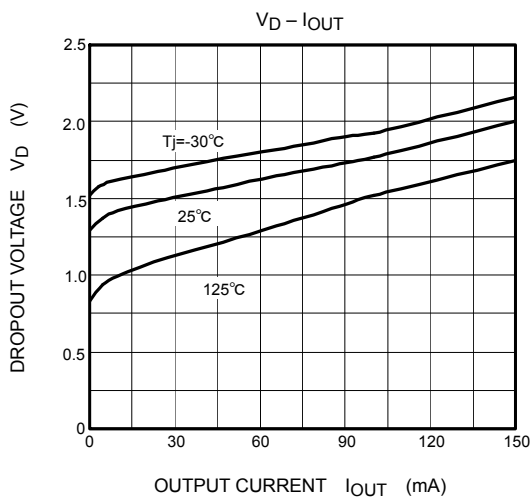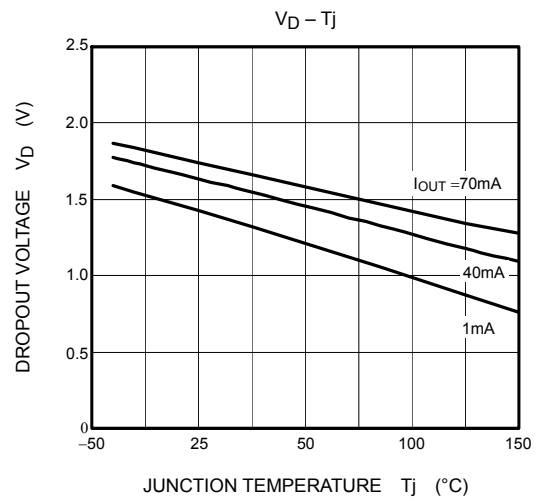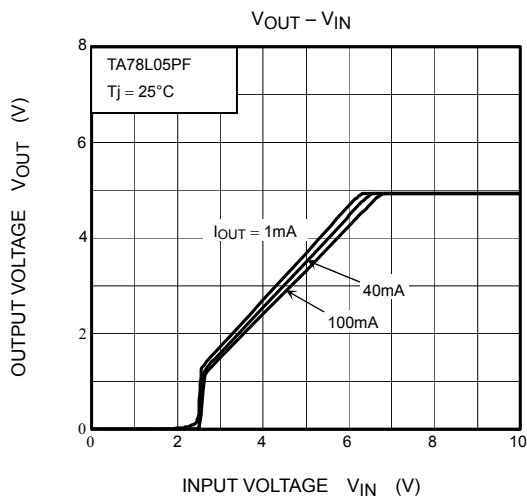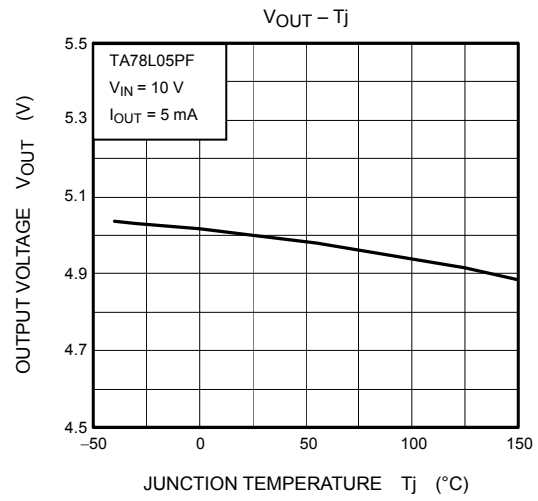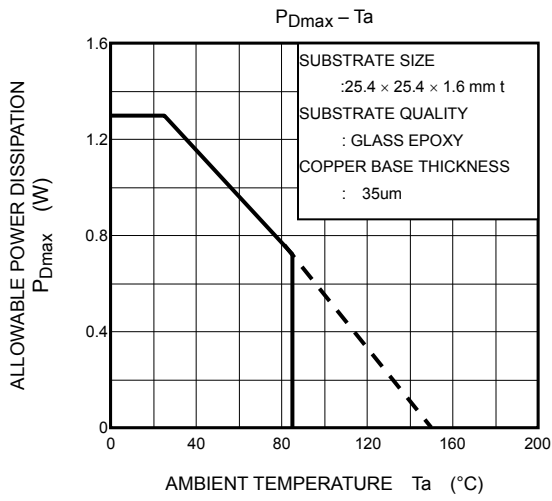## Test Circuit 1/Standard Application
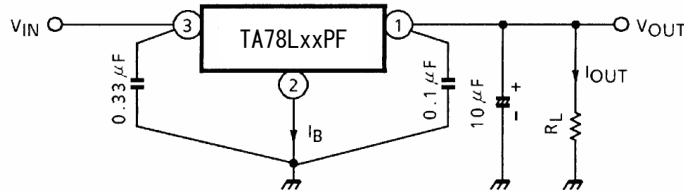
Use capacitors to connect the input terminal and GND and the output terminal and GND.
The capacitances should be determined experimentally. In particular, adequate investigation should be made to ensure there is no problem even in high or low temperatures.
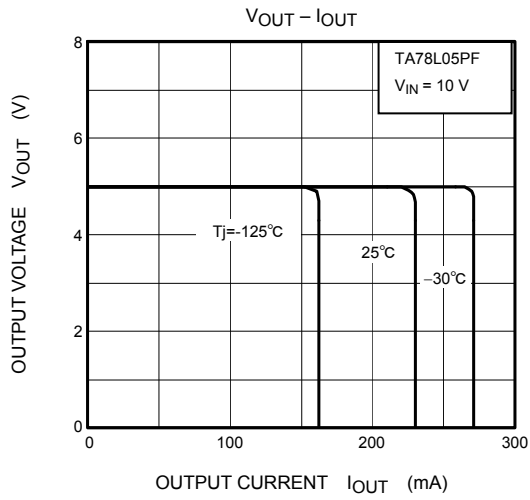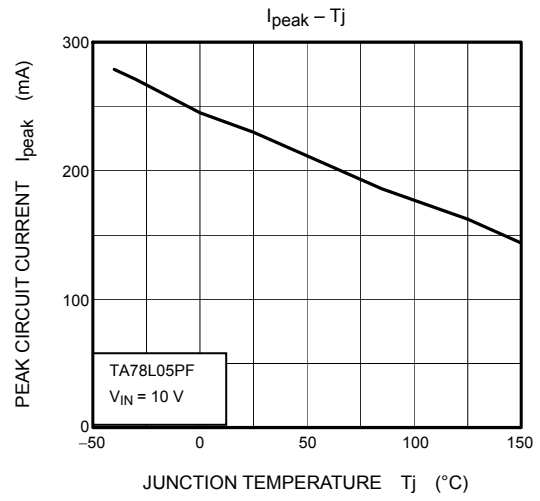
Test Circuit 2

V_NO

Test Circuit 3

R.R.

$P_{Dmax} - Ta$

ALLOWABLE POWER DISSIPATION P_{Dmax} (W) vs AMBIENT TEMPERATURE Ta (°C)

SUBSTRATE SIZE
: 25.4 × 25.4 × 1.6 mm t
SUBSTRATE QUALITY
: GLASS EPOXY
COPPER BASE THICKNESS
: 35um

$V_{OUT} - Tj$

OUTPUT VOLTAGE V_{OUT} (V) vs JUNCTION TEMPERATURE Tj (°C)

TA78L05PF
V_{IN} = 10 V
I_{OUT} = 5 mA

$V_{OUT} - V_{IN}$

OUTPUT VOLTAGE V_{OUT} (V) vs INPUT VOLTAGE V_{IN} (V)

TA78L05PF
Tj = 25°C

I_{OUT} = 1mA
40mA
100mA

$V_D - Tj$

DROPOUT VOLTAGE V_D (V) vs JUNCTION TEMPERATURE Tj (°C)

I_{OUT} =70mA
40mA
1mA

$V_D - I_{OUT}$

DROPOUT VOLTAGE V_D (V) vs OUTPUT CURRENT I_{OUT} (mA)

Tj=-30°C
25°C
125°C

$I_B - Tj$

QUIESCENT CURRENT I_B (mA) vs JUNCTION TEMPERATURE Tj (°C)

TA78L05PF
V_{IN} = 10 V
I_{OUT} = 5 mA

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$I_B - V_{IN}$

$I_{peak} - Tj$

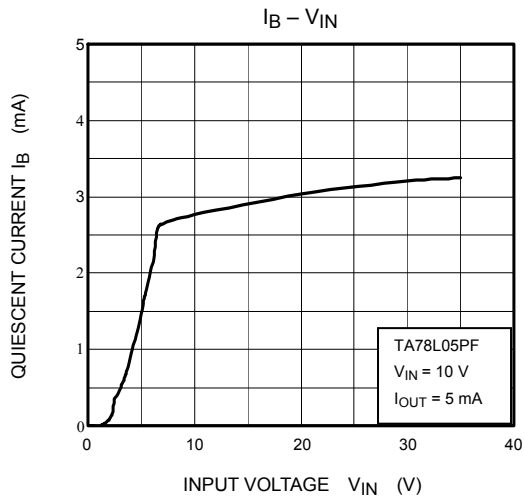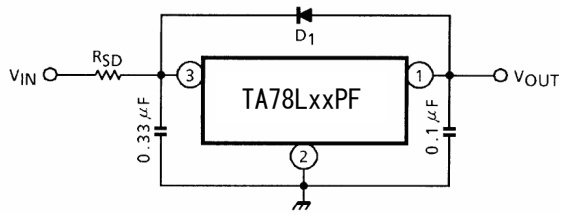$V_{OUT} - I_{OUT}$

Precautions for Use

If a high voltage in excess of the output voltage (typ. value) of the IC is applied to the output terminal of the IC, the IC may be destroyed. To prevent such application of excessive voltage, connect a Zener diode between the output terminal and GND.

D_1 : IC protective diode
When surge voltage is applied to IC output terminal or $V_{IN} < V_{OUT}$ at the time of power ON/OFF, always connect the high speed swithing diode D_1.
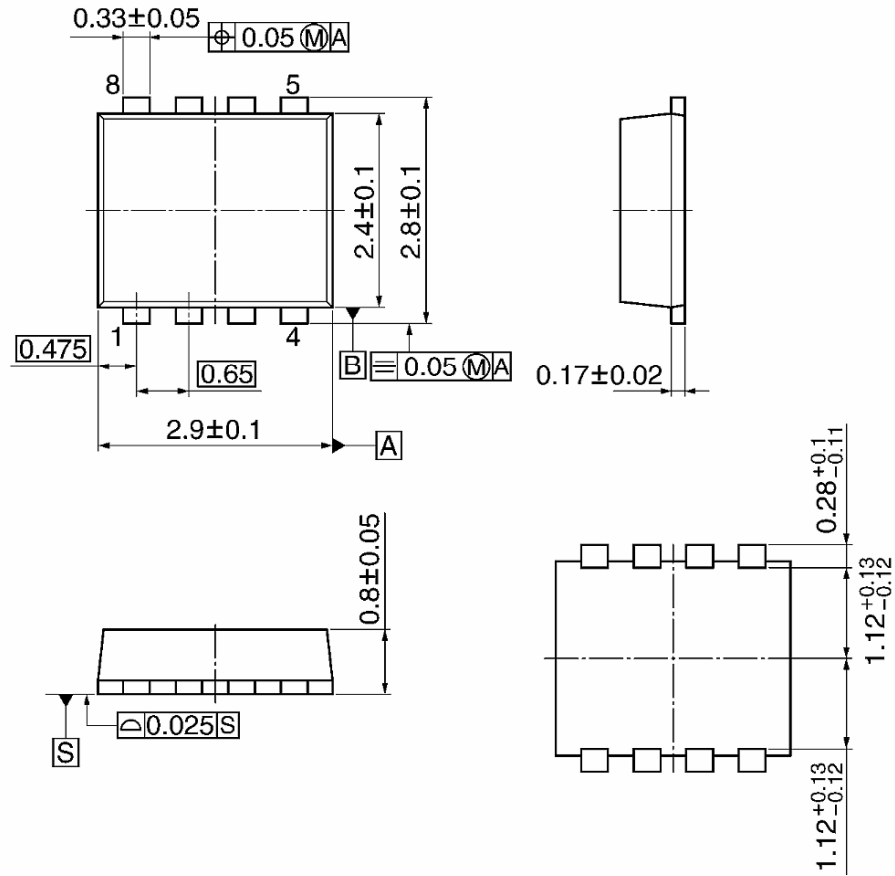
R_{SD} : Power limiting resistor
If V_{IN} is too high, always connect R_{SD} in order to reduce power consumption of IC.

Package Dimensions

SON8-P-0303-0.65 (PS-8)   Unit: mm

Weight: 0.08 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN

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